NSN 5961-01-181-9061

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-181-9061 **Inclosure Material:** Glass **Overall Length:** 0.091 inches **Terminal Length:** 0.062 inches **Overall Diameter:** 0.121 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, dc **Power Rating Per Characteristic:** 0.4 watts small-signal input power, common-collector of standard range **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air and 150.0 degrees celsius junction **Precious Material And Location:** Contact surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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